	Type Hits	Search Text		ı	DBs		Time S
	BRS 7	((aluminum adj nitride) and (aluminum adj oxide)) with gate	USPA	Τ			2002/06
	BRS 10	((aluminum adi nitride) and (aluminum adi oxide)) with gate	USPA"	T; US-PG	PUB	i	2002/06
	BRS 0		EPO;	JPO; DEF	WENT; IBM	_TDB	2002/08
	BRS 1	((aluminum adi nitride) and (aluminum adi oxide)) same gate	EPO:	JPO: DEF	RWENT: IBM		
	BRS 13	((aluminum adj nitride) and (aluminum adj oxide)) and (((high adj dielectric adj constant) or (high with permittivi	USPA	T; US-PG	PUB		2002/06
	BRS 2	(((aluminum adj nitride) and (aluminum adj oxide)) and (((high adj dielectric adj constant) or (high with permittiv	USPA	T; US-PG	PUB		2002/0
	BRS 0	((aluminum adj nitride) and (aluminum adj oxide)) and (((high adj dielectric adj constant) or (high with permittivi	EPO;	JPO; DEF	WENT; IBM	_TDB	2002/0
	BRS 10	((ain) and (ai.sub.2 o.sub.3") with gate	USPA"	Τ			2002/0
	BRS 30	(((aln) and ("al.sub.2 o.sub.3")) same gate) not (((aln) and ("al.sub.2 o.sub.3")) with gate)	USPA"	T; US-PG	PUB		2002/0
	BRS 0	((ain) and (*ai2o3*)) with gate	EPO;	JPO; DEF	RWENT; IBM	_TDB	2002/0
11	BRS 2	((ain) and (ai2o3)) same gate	EPO;	JPO; DEF	RWENT; IBM	_TDB	2002/0
	BRS 6	((ain) and (ai2o3))and gate	EPO;	JPO; DEF	RWENT; IBM	_TDB	2002/0
	BRS 1		USPA"	T			2002/0
	BRS 0		USPA"	T			2002/0
15	BRS 1	((aln) and ("al.sub.2 o.sub.3")) and "4257832"	USPA	T			2002/0
	BRS 1	*6407435*	USPA'	T			2002/0
	BRS 1	*4151537*.PN.	USPA'	T			2002/0
18	BRS 1	*4335391*.PN.	USPA'	T			2002/0
	BRS 1	"6013553".PN.	USPA"	T			2002/0
	BRS 1	"6015739".PN.	USPA'	T			2002/0
	BRS 1	"6297539",PN.	USPA"	T			2002/0
	BRS 1	*4335391*.PN.	USPA"	T			2002/0
	BRS 1	"6013553".PN.	USPA"	T			2002/0
	BRS 1	4199771.pn.	USPA"				2002/0
	BRS 2	(aln or ("al.sub.2 o.sub.3") or (aluminum adj (nitride or oxide))) and "4939571"	USPA"	T; US-PG	PUB		2002/0
	BRS 11	(aln or ("al.sub.2 o.sub.3") or (aluminum adj (nitride or oxide))) with buffer with gate	USPA"	T; US-PG	PUB		2002/0
	BRS 0	(aln or ("al.sub.2 o.sub.3") or (aluminum adj (nitride or oxide))) with blocker with gate	USPA"	T; US-PG	PUB		2002/0
28	BRS 0	(aln or ("al <sb>2</sb> o <sb>3</sb> ") or (aluminum adj (nitride or oxide))) with blocker with gate	USPA	T; US-PG	PUB		2002/0
29	BRS 3	(aln or ("al <sb>2</sb> o <sb>3</sb> ") or (aluminum adj (nitride or oxide))) with buffer with gate			RWENT; IBM		
30	BRS 12	(("al.sub.2 o.sub.3") or (aluminum adj oxide)) and ((aln) or (aluminum adj nitride)) and (sin or (silicon adj nitri	USPA	T; US-PG	PUB		2002/0
31	BRS 9	("al.sub.2o.sub.3") or ("al.sub.2 o.sub.3") or (aluminum adj oxide)) with ((aln) or (aluminum adj nitride)) with (USPA	T; US-PG	PUB		2002/0
32	BRS 0	(("al.sub.2o.sub.3") or ("al.sub.2 o.sub.3") or (aluminum adj oxide)) with ((aln) or (aluminum adj nitride)) with	USPA	T; US-PG	PUB		2002/0
33	BRS 0	(("al.sub.2o.sub.3") or ("al.sub.2 o.sub.3") or (aluminum adj oxide)) with ((aln) or (aluminum adj nitride)) with					2002/0
	BRS 0	((("al.sub.2o.sub.3") or ("al.sub.2 o.sub.3") or (aluminum adj oxide)) with ((aln) or (aluminum adj nitride)) with	USPA	T; US-PG	PUB		2002/0
	BRS 0	((("al.sub.2o.sub.3") or ("al.sub.2 o.sub.3") or (aluminum adj oxide)) with ((aln) or (aluminum adj nitride)) with					2002/0
	BRS 0	(nishizawa in.) and (zaidan.as.) and (aluminum adj (oxide or nitride))		JPO; DEF			2002/0
	BRS 0	(nishizawa.in.) and (zaidan.as.) and (aln)		JPO; DEF		***********	2002/0
	BRS 0	(nishizawa.in.) and (zaidan.as.) and (al2o3)	EPO:	JPO: DEF	RWENT		2002/0

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